



PART B — (5 × 16 = 80 marks)

11. (a) (i) What are the essential concepts of classical free theory of metals and quantum free electron theory of metals? Discuss the success and failures of both the theories. (6)
- (ii) Derive an expression for electrical conductivity of metals based on the concepts of classical free electron theory. (6)
- (iii) A copper wire 3.2 mm in diameter, carries a current of 0.5 A. Valency of copper is one. Atomic weight and density of copper are 63.5 and 8900 kg/m<sup>3</sup> respectively. Calculate the speed of conduction electrons. (4)

Or

- (b) (i) What is meant by Fermi energy in metals? Based on quantum theory derive an expression for density of energy states, hence obtain an expression for Fermi energy. (12)
- (ii) The Fermi energy for Al is 11.7 eV Find the probability that the state with energy 11.8 eV be occupied at 0 K and at room temperature (300 K.) (4)
12. (a) (i) Explain with necessary theory the Hall method of identification of p-type or n-type semiconductors and to determine the mobility of charge carriers. (12)
- (ii) A rectangular sample of n-type germanium has a donor density of 10<sup>21</sup>/m<sup>3</sup>. It is arranged in a Hall experiment having a magnetic field of 0.4 T perpendicular to the plane of the sample. Find the Hall voltage when the current is 5 A and the sample is 3 mm thick. If the magnetic field is reduced to half the value what will be the Hall voltage. (4)

Or

- (b) (i) Derive an expression for electrical conductivity of an intrinsic semiconductor. Describe the experiment to determine the band gap of the semiconductor. (12)
- (ii) The forbidden energy gap of intrinsic silicon semiconductor is 1.1 eV. Compare the density of conduction electrons at 27°C and at 37°C. (4)
13. (a) (i) Define the terms orbital magnetic moment, spin magnetic moment and Bohr magneton. (6)
- (ii) Explain the hysteresis property exhibited by ferromagnetic materials using domain theory. (10)

Or

- (b) (i) Explain the important properties exhibited by superconductors. (12)
- (ii) Explain the principle of magnetic levitation. (4)

14. (a) (i) Explain the mechanism of polarization in ionic crystals and polar materials. (12)
- (ii) The atomic weight and density of sulphur are 32 and 2080 kgm<sup>-3</sup> respectively. The electronic polarizability of sulphur atom is  $3.28 \times 10^{-40}$  F m<sup>2</sup>. Solid sulphur has cubical symmetry. Calculate its dielectric constant. (4)

Or

- (b) (i) Explain in detail the use of dielectric materials in capacitors and transformer cores. (12)
- (ii) Explain dielectric loss and find an expression for dielectric power loss. (4)
15. (a) (i) Explain the optical phenomenon of birefringence. Give the technological applications of this phenomenon. (8)
- (ii) Describe the chemical vapour deposition method of preparing nano materials. What are the limitations of this method? (8)

Or

- (b) (i) What are metallic glasses? What are the characteristic properties exhibited by them. Give its usefulness as transformer core material. (12)
- (ii) Give the applications of biomaterials in the field of ophthalmology. (4)